

IPG20N06S2L50ATMA1

IPG20N06S2L50ATMA1 Information

Part NumberIPG20N06S2L50ATMA1ManufacturerInfineon Technologies

Category Discrete Semiconductor Products
Transistors - FETs, MOSFETs - Arrays

Description MOSFET 2N-CH 55V 20A TDSON-8-4

Package 8-PowerVDFN

For the pricing/inventory/lead time, please contact

us

For Reference Only

Website: https://www.heisener.com
E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









IPG20N06S2L50ATMA1 Specifications

Manufacturer Part Number	IPG20N06S2L50ATMA1
Manufacturer	Infineon Technologies
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Arrays
Package	8-PowerVDFN
Series	OptiMOS?
FET Type	2 N-Channel (Dual)
FET Feature	Logic Level Gate
Drain to Source Voltage (Vdss)	55V
Current - Continuous Drain (Id) @ 25°C	20A
Rds On (Max) @ Id, Vgs	50 mOhm @ 15A, 10V
Vgs(th) (Max) @ Id	2V @ 19μA
Gate Charge (Qg) (Max) @ Vgs	17nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	560pF @ 25V
Power - Max	51W
Operating Temperature	-55°C ~ 175°C (TJ)
Mounting Type	Surface Mount
Package / Case	8-PowerVDFN
Supplier Device Package	PG-TDSON-8-4
	Report errors?

IPG20N06S2L50ATMA1 Guarantees



Ouality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

IPG20N06S2L50ATMA1 Payment Methods



















IPG20N06S2L50ATMA1 Shipping Methods













If you have any question about IPG20N06S2L50ATMA1, please do not hesitate to contact us!

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